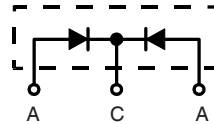


# Common Cathode Fast Recovery Epitaxial Diode (FRED)

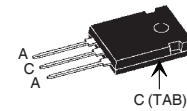
## DSEK 60

$I_{FAVM} = 2 \times 34 \text{ A}$   
 $V_{RRM} = 200 \text{ V}$   
 $t_{rr} = 35 \text{ ns}$

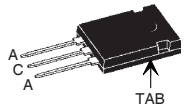
$V_{RSM}$ V	$V_{RRM}$ V	Type
200	200	DSEK 60-02A
200	200	DSEK 60-02AR



TO-247 AD  
Version A



ISOPLUS 247™  
Version AR



A = Anode, C = Cathode

Symbol	Test Conditions	Maximum Ratings per leg	
$I_{FRMS}$	$T_{VJ} = T_{VJM}$	50	A
$I_{FAVM}$	* $T_C = 115^\circ\text{C}$ ; rectangular, d = 0.5	34	A
$I_{FRM}$	$t_p < 10 \mu\text{s}$ ; rep. rating, pulse width limited by $T_{VJM}$	375	A
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ ; t = 10 ms (50 Hz), sine	325	A
	t = 8.3 ms (60 Hz), sine	350	A
	$T_{VJ} = 150^\circ\text{C}$ ; t = 10 ms (50 Hz), sine	290	A
	t = 8.3 ms (60 Hz), sine	310	A
$I^2t$	$T_{VJ} = 45^\circ\text{C}$ t = 10 ms (50 Hz), sine	530	A <sup>2</sup> s
	t = 8.3 ms (60 Hz), sine	510	A <sup>2</sup> s
	$T_{VJ} = 150^\circ\text{C}$ ; t = 10 ms (50 Hz), sine	420	A <sup>2</sup> s
	t = 8.3 ms (60 Hz), sine	400	A <sup>2</sup> s
$T_{VJ}$		-40...+150	°C
$T_{VJM}$		150	°C
$T_{stg}$		-40...+150	°C
$P_{tot}$	$T_C = 25^\circ\text{C}$	125	W
$M_d$ *	Mounting torque with screw M3	0.45-0.55/4-5	Nm/lb.in.
	Mounting torque with screw M3.5	0.45-0.55/4-5	Nm/lb.in.
$V_{ISOL}$ **	50/60 Hz, RMS, t = 1 minute, leads-to-tab	2500	V~
Weight		6	g

\* Version A only; \*\* Version AR only

Symbol	Test Conditions	Characteristic Values per leg	
		typ.	max.
$I_R$	$T_{VJ} = 25^\circ\text{C}$ $V_R = V_{RRM}$	200	$\mu\text{A}$
	$T_{VJ} = 25^\circ\text{C}$ $V_R = 0.8 \cdot V_{RRM}$	50	$\mu\text{A}$
	$T_{VJ} = 125^\circ\text{C}$ $V_R = 0.8 \cdot V_{RRM}$	5	mA
$V_F$	$I_F = 30 \text{ A}$ ; $T_{VJ} = 150^\circ\text{C}$	0.85	V
	$T_{VJ} = 25^\circ\text{C}$	1.10	V
$V_{TO}$	For power-loss calculations only	0.72	V
$r_T$	$T_{VJ} = T_{VJM}$	4.2	$\text{m}\Omega$
$R_{thJC}$ $R_{thCH}$		0.5	1 K/W K/W
$t_{rr}$	$I_F = 1 \text{ A}$ ; $-di/dt = 100 \text{ A}/\mu\text{s}$ ; $V_R = 30 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$	35	50ns
$I_{RM}$	$V_R = 100 \text{ V}$ ; $I_F = 30 \text{ A}$ ; $-di_F/dt = 100 \text{ A}/\mu\text{s}$	4	5 A
	$L \leq 0.05 \mu\text{H}$ ; $T_{VJ} = 25^\circ\text{C}$		

\*  $I_{FAVM}$  rating includes reverse blocking losses at  $T_{VJM}$ ,  $V_R = 0.8 V_{RRM}$ , duty cycle d = 0.5  
Data according to IEC 60747 refer to a single diode unless otherwise stated.  
IXYS reserves the right to change limits, test conditions and dimensions

### Features

- International standard package JEDEC TO-247 AD
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low  $I_{RM}$ -values
- Soft recovery behavior
- Epoxy meets UL 94V-0 flammability classification
- Version AR isolated and UL registered E153432

### Applications

- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

### Advantages

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses
- Operating at lower temperature or space saving by reduced cooling

D1

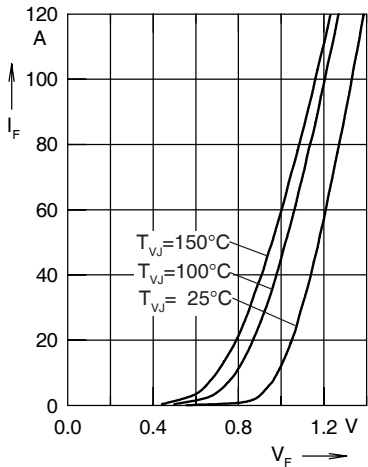


Fig. 1 Forward current  $I_F$  versus  $V_F$

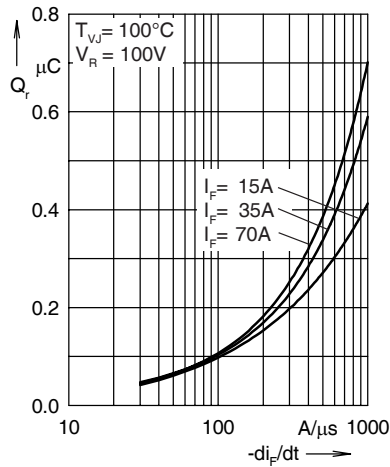


Fig. 2 Typ. reverse recovery charge  $Q_r$  versus  $-di_F/dt$

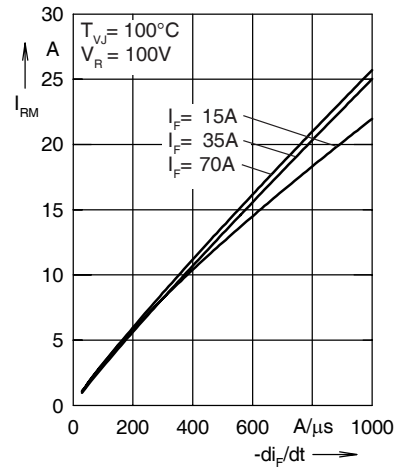


Fig. 3 Typ. peak reverse current  $I_{RM}$  versus  $-di_F/dt$

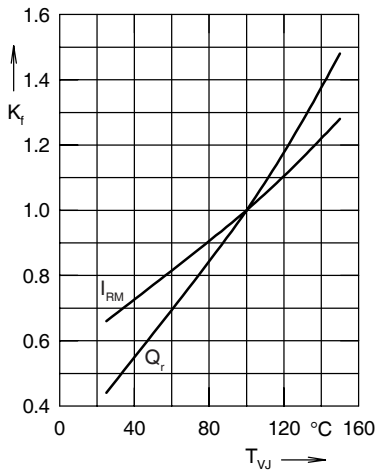


Fig. 4 Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus  $T_{VJ}$

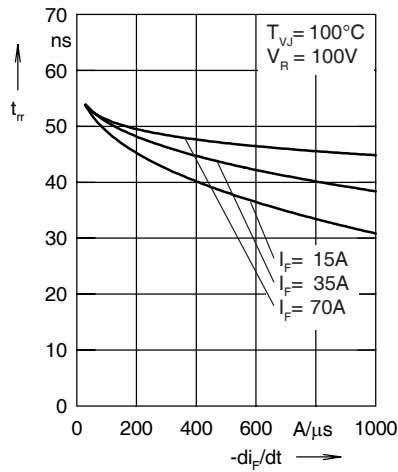


Fig. 5 Typ. recovery time  $t_{tr}$  versus  $-di_F/dt$

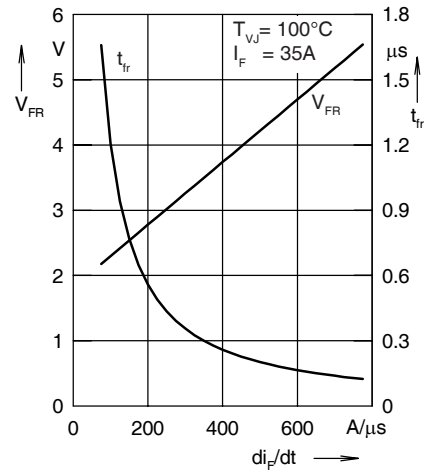


Fig. 6 Typ. peak forward voltage  $V_{FR}$  and  $t_{tr}$  versus  $di_F/dt$

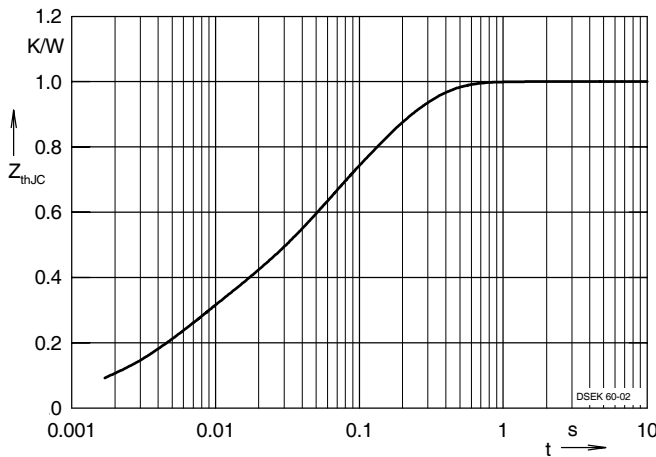
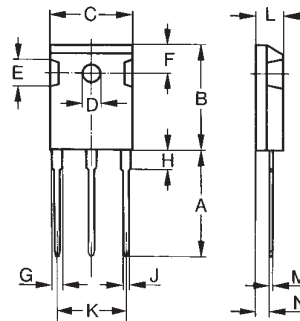


Fig. 7 Transient thermal impedance junction to case

### Dimensions



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	19.81	20.32	0.780	0.800
B	20.80	21.46	0.819	0.845
C	15.75	16.26	0.610	0.640
D	3.55	3.65	0.140	0.144
E	4.32	5.49	0.170	0.216
F	5.4	6.2	0.212	0.244
G	1.65	2.13	0.065	0.084
H	-	4.5	-	0.177
J	1.0	1.4	0.040	0.055
K	10.8	11.0	0.426	0.433
L	4.7	5.3	0.185	0.209
M	0.4	0.8	0.016	0.031
N	2.2	2.54	0.087	0.102

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